NSN 5961-01-003-0580

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-003-0580 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.290 inches **Overall Height:** 0.290 inches **Overall Width:** 0.510 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Emitter **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 65.0 collector to base voltage/static/emitter open **Current Rating Per Characteristic:** 9.00 amperes all primaries **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 4 ferrule Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

No

NSN 5961-01-003-0580 Transistor - Page 2 of 2



Fiig:

A110a0